

QSI LASER DIODE

SPECIFICATIONS FOR APPROVAL

Customer :

Model : QL65F7S-A/B/C

Signature of Approval

Approved by _____

Checked by _____

Issued by _____

Approval by Customer



QSI Co., Ltd.

315-9, Cheonheung-ri, Sungger-eup,
Cheonan-city, Chungnam, Korea 330-836

WWW.QSILaser.com

QL65F7S-A/B/C

InGaAIP Laser Diode

Quantum Semiconductor International Co., Ltd.

Ver. 1 JAN. 2004

◆ OVERVIEW

QL65F7S-A/B/C is a MOCVD grown 650nm band *InGaAIP* laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 10mW and low operating current for optoelectronic devices such as Optical Pick-up & Bar Code Reader.

◆ APPLICATION

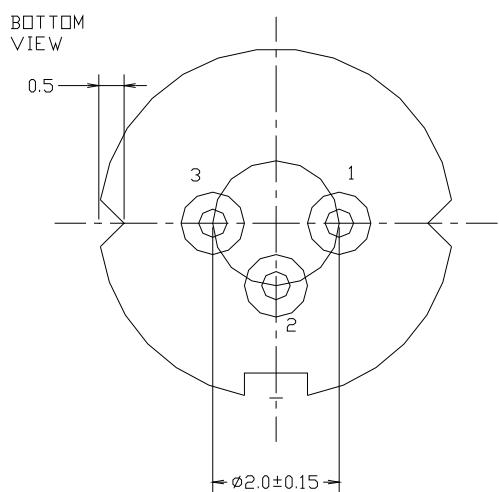
- Optical Pick-up
- Laser Module
- Bar Code Reader

◆ FEATURES

- Visible Light Output : $\lambda_p = 650$ nm
- Optical Power Output : 10mW CW
- Package Type : TO-18 (5.6mm ϕ)
- Built-in Photo Diode for Monitoring Laser Diode

◆ ELECTRICAL CONNECTION

Bottom View



Pin Configuration

A	LD cathode, PD anode (Fig. 1)
B	LD , PD anode (Fig. 2)
C	LD anode, PD cathode (Fig. 3)

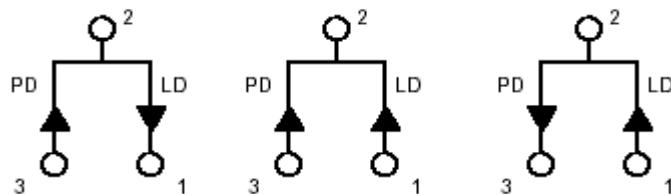


Fig. 1
QL65F7SA

Fig. 2
QL65F7SB

Fig. 3
QL65F7SC

◆ ABSOLUTE MAXIMUM RATING at Tc=25°C

Items	Symbols	Values	Unit
Optical Output Power	P	12	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	Topr	-10 ~ +70	°C
Storage Temperature	Tstg	-40 ~ +85	°C

◆ ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25°C

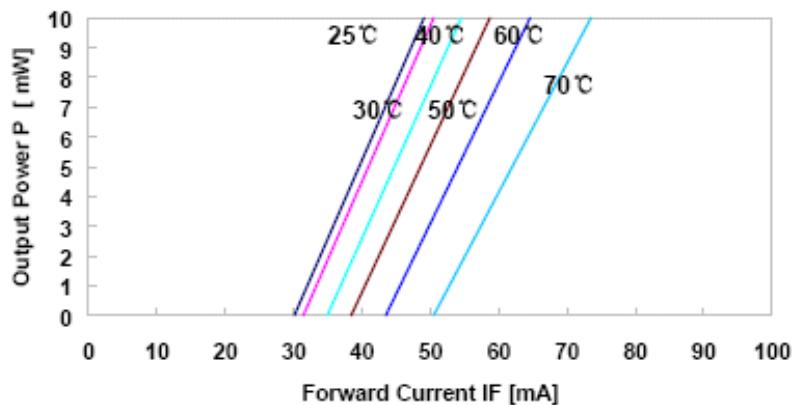
Items	Symbols	Min.	Typ.	Max.	Unit	Condition
Optical Output Power	Po	-	10	-	mW	-
Threshold Current	Ith	-	40	50	mA	-
Operating Current	Iop	-	60	80	mA	Po=10mW
Operating Voltage	Vop	-	2.3	2.6	V	Po=10mW
Lasing Wavelength	λp	645	655	660	nm	Po=10mW
Beam Divergence	θ	6	9	12	deg	Po=10mW
	θ ⊥	20	25	30	deg	Po=10mW
Beam Angle	Δθ	-	-	±1.5	deg	Po=10mW
	Δθ ⊥	-	-	±2.5	deg	Po=10mW
Monitor Current	Im	0.1	0.2	0.5	mA	Po=10mW
Optical Distance	ΔX, ΔY, ΔZ	-	-	±60	μm	-

NOTICE : QL65F7S-A/B/C to be operated on APC

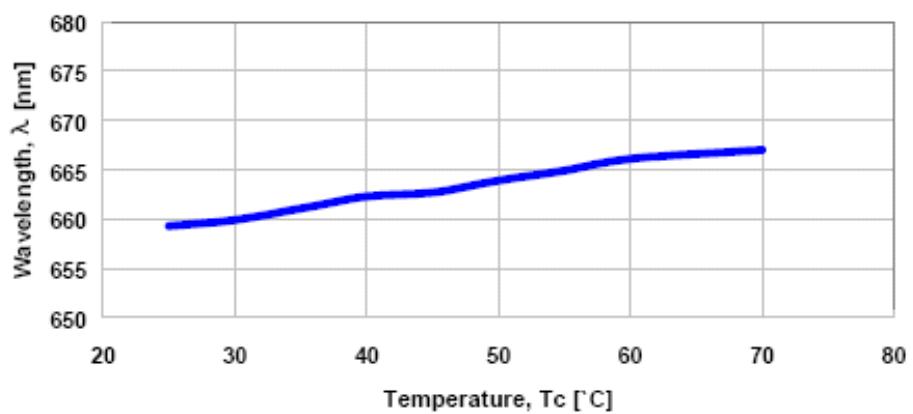
The above product specifications are subject to change without notice.

◆ EXAMPLE of REPRESENTATIVE CHARACTERISTICS

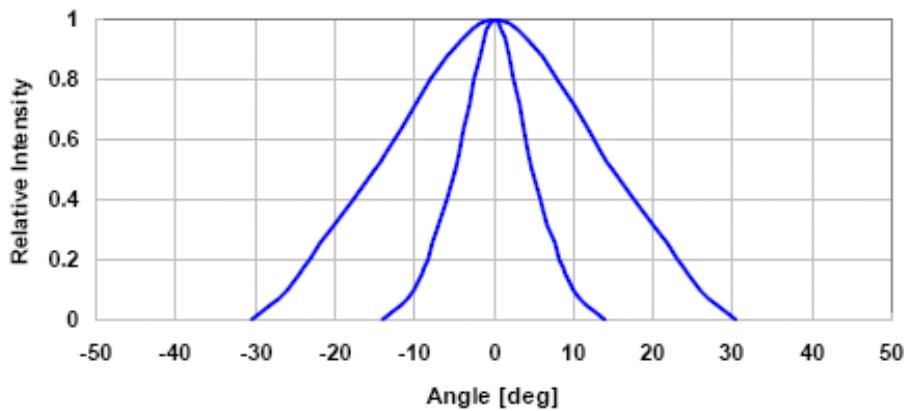
Optical Power vs. Forward Current



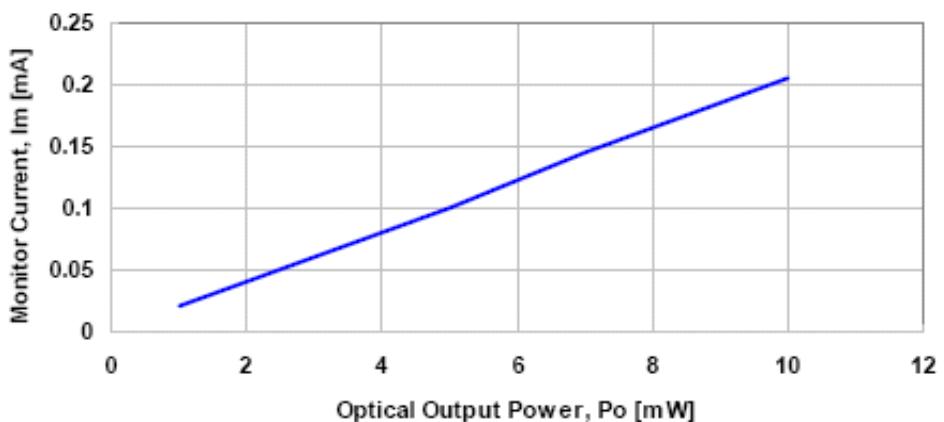
Wavelength vs. Temperature



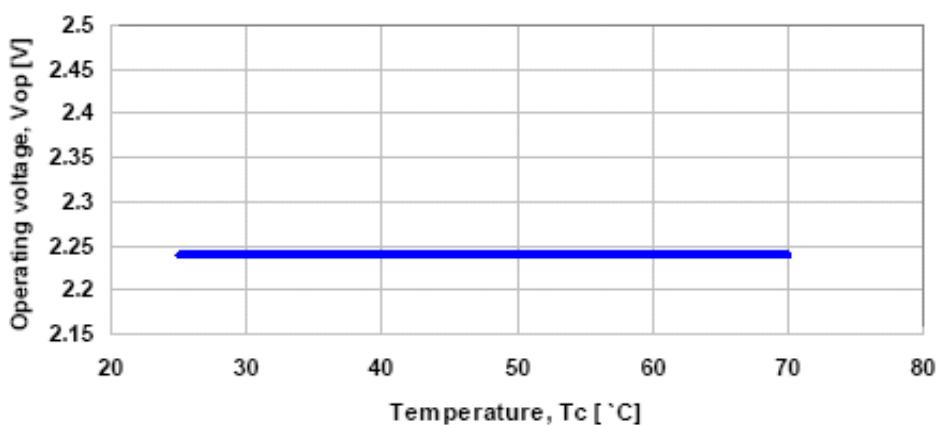
Far Field Pattern



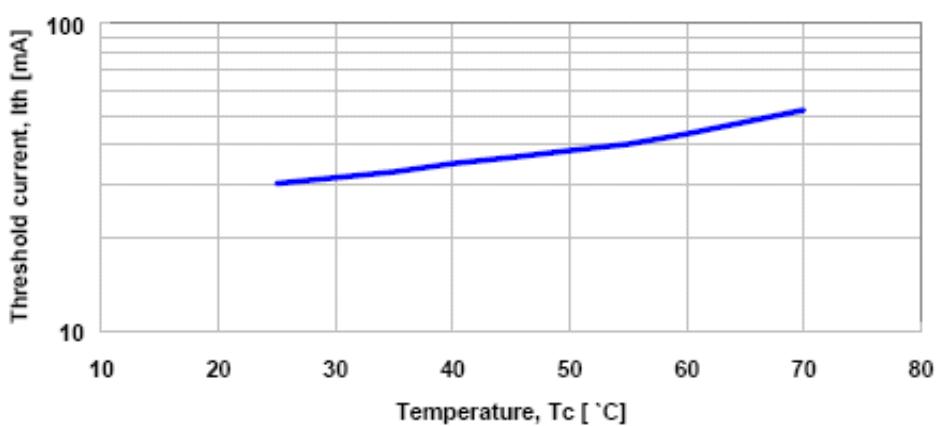
Monitor Current vs. Optical Output Power



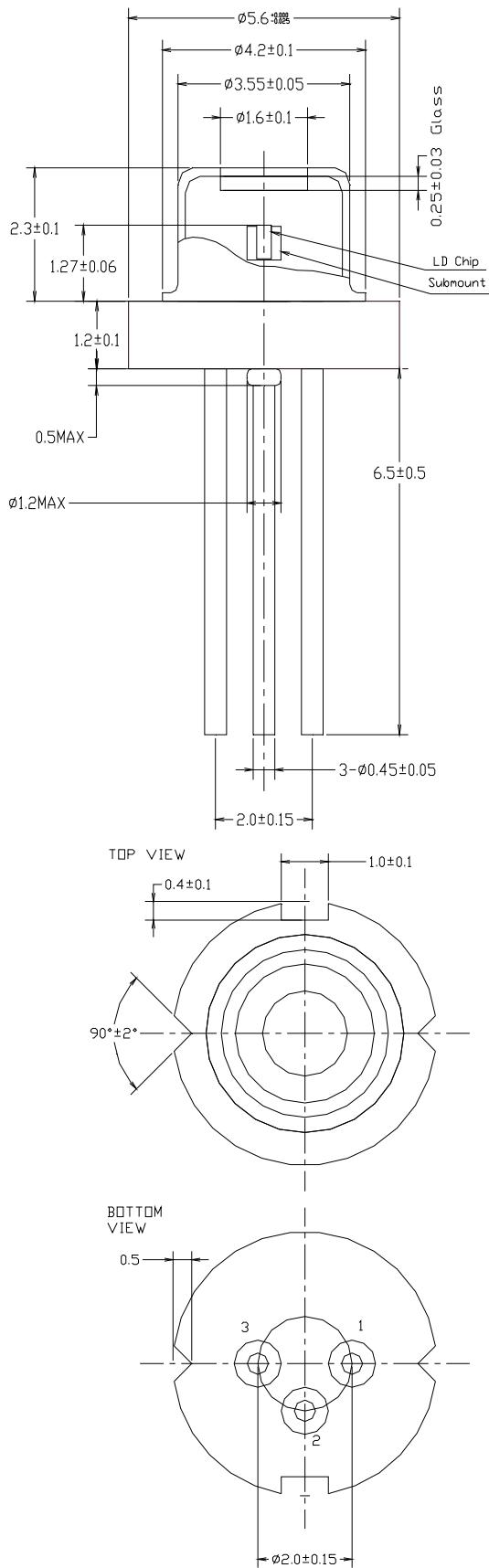
Operating Voltage vs. Temperature



Threshold Current vs. Temperature



◆ PACKAGE DIMENSION



◆PACKING

